INJ0011AX SERIES

High speed switching Silicon P-channel MOSFET

DESCRIPTION

INJ0011AX is a Silicon P-channel MOSFET.

This product is most suitable for low voltage use such as portable machinery, because of low voltage drive and low on resistance.

FEATURE

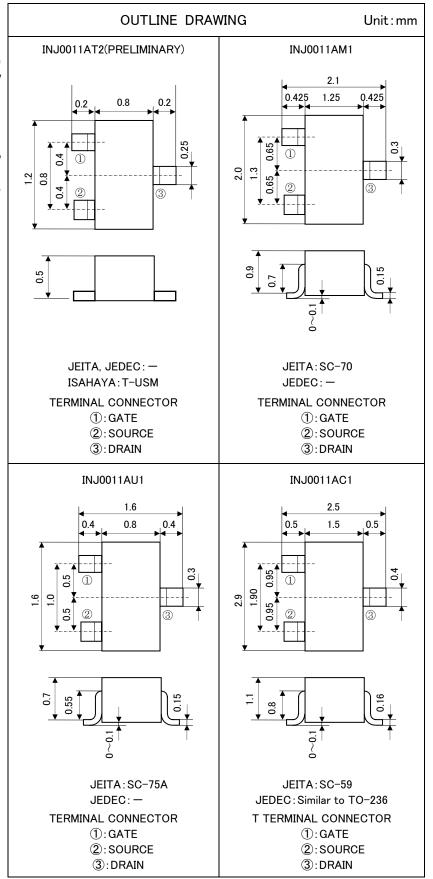
- •Input impedance is high, and not necessary to consider a drive electric current.
- Vth is low, and drive by low voltage is possible.
 Vth=-1.0 ~-2.0V
- Low on Resistance. $R_{DS}(on)=7.0\,\Omega\,(TYP)@I_D=-100mA,\,V_{GS}=-4.0V$ $R_{DS}(on)=4.8\,\Omega\,(TYP)@I_D=-100mA,\,V_{GS}=-10V$
- ·High speed switching.
- ·Small package for easy mounting.

APPLICATION

High speed switching , Analog switching

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EQUIVALENT CIRCUIT



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High speed switching Silicon P-channel MOSFET

MAXIMUM RATING(Ta=25°C)

SYMBOL	PARAMETER	RATING				
		INJ0001AT2	INJ0001AU1	INJ0001AM1	INJ0001AC1	UNIT
V _{DSS}	Drain-source voltage	-50				
V_{GSS}	Gate-source voltage	±20				
Ι _D	Drain current	-100				
P _D	Total power dissipation (Ta=25°C)	125(※)	150	200		mW
Tch	Channel temperature	+125	+150			°C
Tstg	Range of Storage temperature	−55 ~ +125	−55 ~ +150			°C

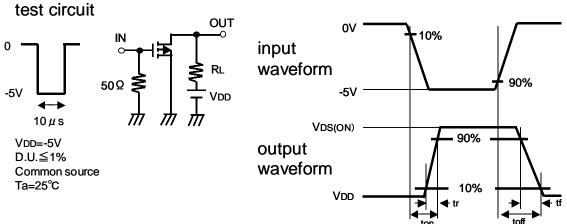
ELECTRICAL CHARACTERISTICS (Ta=25°C)

※package mounted on 9mm x 19mm x 1mm glass-epoxy substrate.

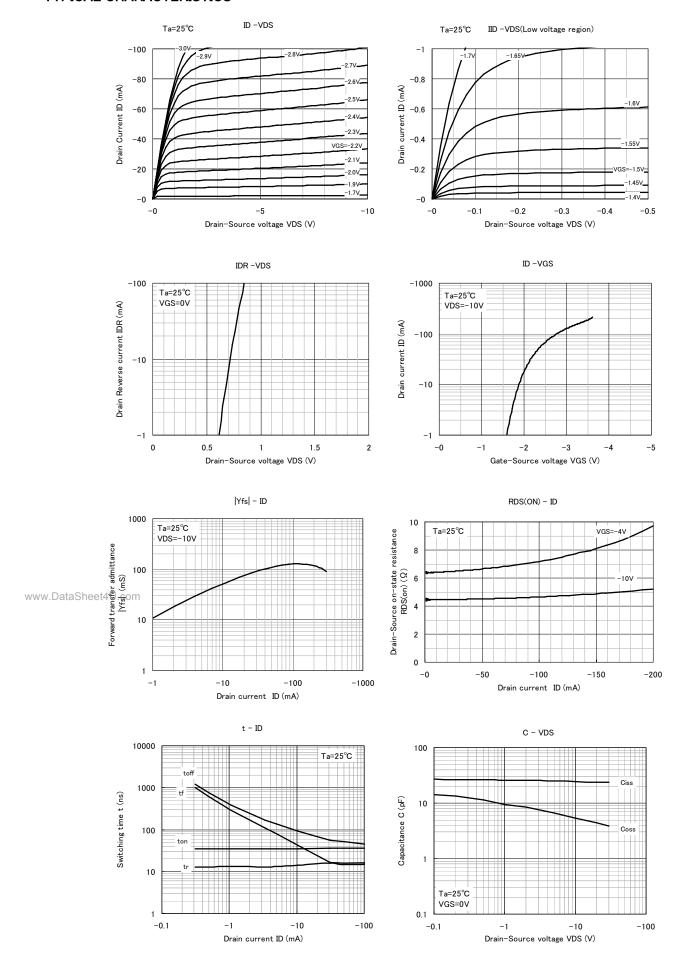
SYMBOL	PARAMETER	TEST CONDITION	LIMIT			LINIT
			MIN	TYP	MAX	UNIT
V _{(BR)DSS}	Drain-source breakdown voltage	$I_D=-100 \mu A, V_{GS}=0V$	-50	_	_	V
I _{GSS}	Gate-source leak current	$V_{GS} = \pm 20V, V_{DS} = 0V$	_	_	±10	μΑ
I _{DSS}	Zero gate voltage drain current	V _{DS} =-50V ,V _{GS} =0V	_	_	-1.0	μΑ
V_{th}	Gate threshold voltage	$I_D = -250 \mu$ A, $V_{DS} = V_{GS}$	-1.0	_	-2.0	V
Y _{fs}	Forward transfer admittance	V _{DS} =-10V, I _D =-100mA	-	145	-	mS
R _{DS(ON)}	Static drain-source on-state	I _D =-100mA, V _{GS} =-4.0V	_	7.0	-	Ω
	resistance	I _D =-100mA, V _{GS} =-10V	_	4.8	_	75
Ciss	Input capacitance	V _{DS} =-10V, V _{GS} =0V,f=1MHz	_	25	_	pF
Coss	Output capacitance	V _{DS} =-10V, V _{GS} =0V,f=1MHz	-	6.0	-	pF
ton	6 7 1 7	V _{DD} =-5V , I _D =-10mA	_	35	-	ns
toff	- Switching time	V _{GS} =0~-5V	_	90	_	

Switching time test condition

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TYPICAL CHARACTERISTICS





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